Microsemi Corporation - AFS600-PQG208I Datasheet

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	110592
Number of I/O	95
Number of Gates	600000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/afs600-pqg208i

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Fusion Device Family Overview

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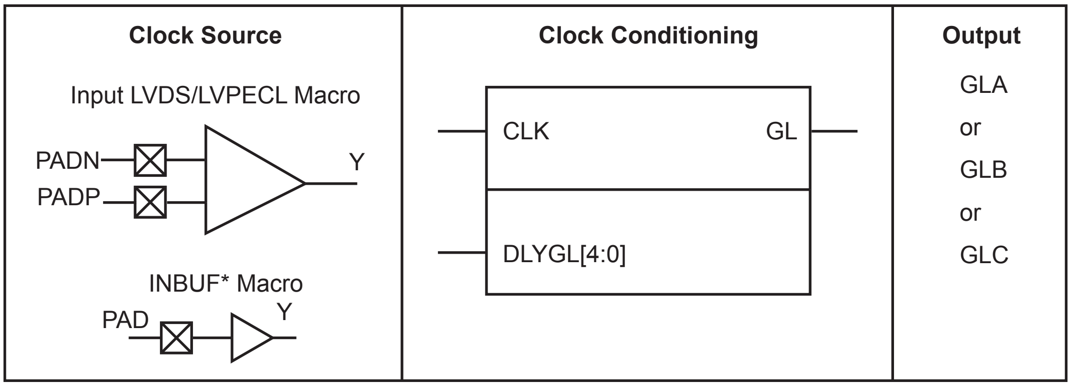
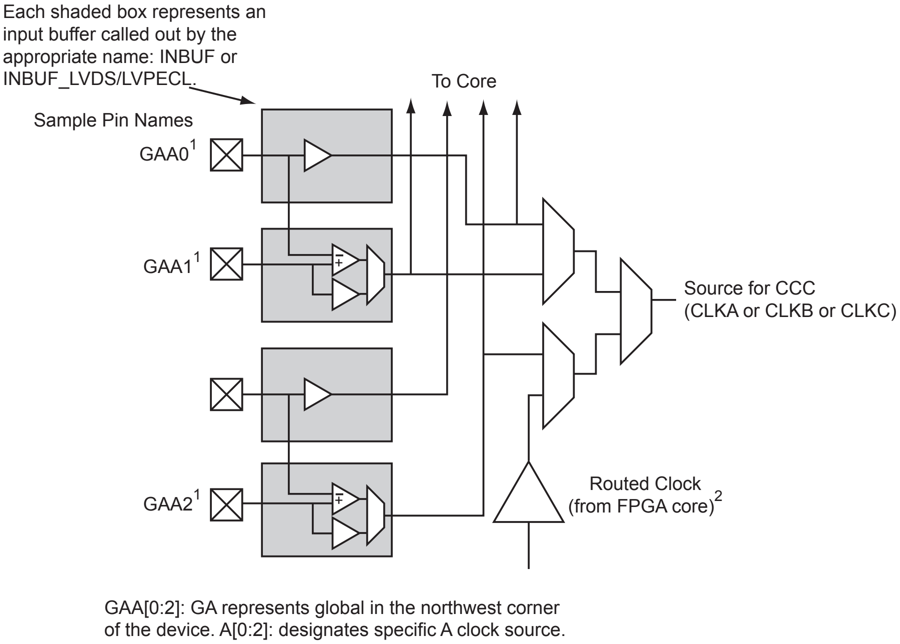


Figure 2-21 • **Fusion CCC Options: Global Buffers with Programmable Delay**

Global Input Selections

Each global buffer, as well as the PLL reference clock, can be driven from one of the following (Figure 2-22):

- 3 dedicated single-ended I/Os using a hardwired connection
- 2 dedicated differential I/Os using a hardwired connection
- The FPGA core



Notes:

1. *Represents the global input pins. Globals have direct access to the clock conditioning block and are not routed via the FPGA fabric. Refer to the "User I/O Naming Convention" section on page 2-158 for more information.*
2. *Instantiate the routed clock source input as follows:*
   a) Connect the output of a logic element to the clock input of the PLL, CLKDLY, or CLKINT macro.
   b) Do not place a clock source I/O (INBUF or INBUF_LVPECL/LVDS) in a relevant global pin location.
3. *LVDS-based clock sources are available in the east and west banks on all Fusion devices.*

Figure 2-22 • **Clock Input Sources Including CLKBUF, CLKBUF_LVDS/LVPECL, and CLKINT**

Fusion uses a remote diode as a temperature sensor. The Fusion Temperature Monitor uses a differential input; the AT pin and ATRTN (AT Return) pin are the differential inputs to the Temperature Monitor. There is one Temperature Monitor in each Quad. A simplified block diagram is shown in Figure 2-77.

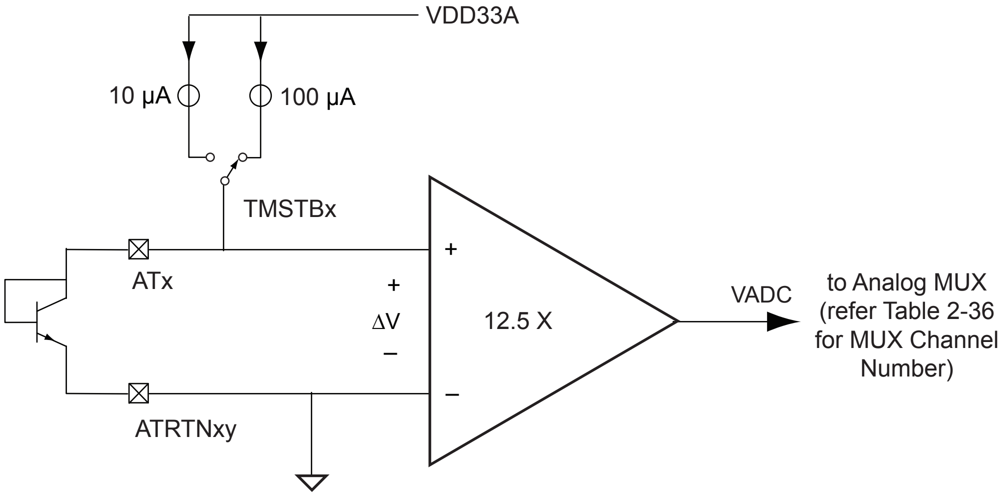


***Figure 2-77* • Block Diagram for Temperature Monitor Circuit**

The Fusion approach to measuring temperature is forcing two different currents through the diode with a ratio of 10:1. The switch that controls the different currents is controlled by the Temperature Monitor Strobe signal, TMSTB. Setting TMSTB to '1' will initiate a Temperature reading. The TMSTB should remain '1' until the ADC finishes sampling the voltage from the Temperature Monitor. The minimum sample time for the Temperature Monitor cannot be less than the minimum strobe high time minus the setup time. Figure 2-78 shows the timing diagram.

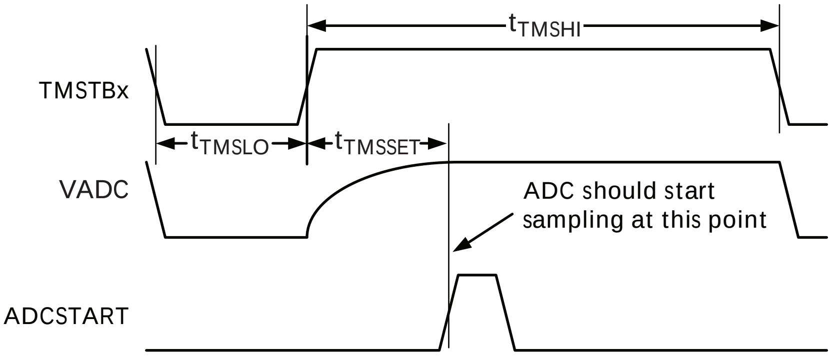


***Figure 2-78* • Timing Diagram for the Temperature Monitor Strobe Signal**

Note: When the IEEE 1149.1 Boundary Scan EXTEST instruction is executed, the AG pad drive strength ceases and becomes a 1 µA sink into the Fusion device.

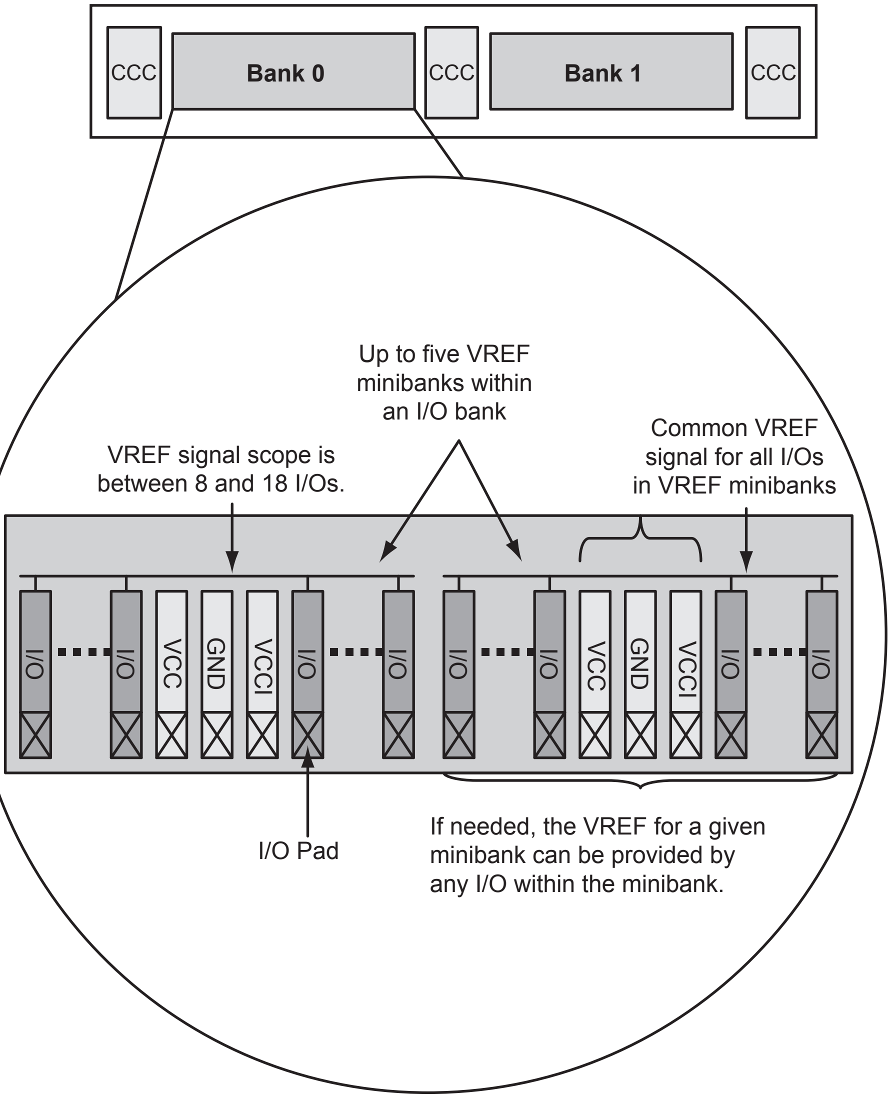


Figure 2-99 • **Fusion Pro I/O Bank Detail Showing VREF Minibanks (north side ofAFS600 and AFS1500)**

Table 2-67 • **I/O Standards Supported by Bank Type**

I/O Bank	Single-Ended I/O Standards	Differential I/O Standards	Voltage-Referenced	Hot-Swap
Standard I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V / 1.8 V / 1.5 V, LVCMOS 2.5/5.0 V	–	–	Yes
Advanced I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V / 1.8 V / 1.5 V, LVCMOS 2.5/5.0 V, 3.3 V PCI / 3.3 V PCI-X	LVPECL and LVDS	–	–
Pro I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V / 1.8 V / 1.5 V, LVCMOS 2.5/5.0 V, 3.3 V PCI / 3.3 V PCI-X	LVPECL and LVDS	GTL+ 2.5 V / 3.3 V, GTL 2.5 V / 3.3 V, HSTL Class I and II, SSTL2 Class I and II, SSTL3 Class I and II	Yes

Table 2-71 • Fusion Standard and Advanced I/O Features

I/O Bank Voltage (typical)	Minibank Voltage (typical)	LVTTL/LVCMOS 3.3 V	LVCMOS 2.5 V	LVCMOS 1.8 V	LVCMOS 1.5 V	3.3 V PCI / PCI-X	GTL + (3.3 V)	GTL + (2.5 V)	GTL (3.3 V)	GTL (2.5 V)	HSTL Class I and II (1.5 V)	SSTL2 Class I and II (2.5 V)	SSTL3 Class I and II (3.3 V)	LVDS (2.5 V ± 5%)	LVPECL (3.3 V)
3.3 V	–	☐	▨	▨	▨	☐	▨	▨	▨	▨	▨	▨	▨	▨	☐
	0.80 V	☐	▨	▨	▨	☐	▨	▨	☐	▨	▨	▨	▨	▨	☐
	1.00 V	☐	▨	▨	▨	☐	☐	▨	▨	▨	▨	▨	▨	▨	☐
	1.50 V	☐	▨	▨	▨	☐	▨	▨	▨	▨	▨	▨	☐	☐	☐
2.5 V	–	▨	☐	▨	▨	▨	▨	▨	▨	▨	▨	▨	▨	▨	▨
	0.80 V	▨	☐	▨	▨	▨	▨	▨	▨	☐	▨	▨	▨	☐	▨
	1.00 V	▨	☐	▨	▨	▨	▨	☐	▨	▨	▨	▨	▨	☐	▨
	1.25 V	▨	☐	▨	▨	▨	▨	▨	▨	▨	▨	☐	▨	☐	▨
1.8 V	–	▨	▨	☐	▨	▨	▨	▨	▨	▨	▨	▨	▨	▨	▨
1.5 V	–	▨	▨	▨	☐	▨	▨	▨	▨	▨	▨	▨	▨	▨	▨
	0.75 V	▨	▨	▨	☐	▨	▨	▨	▨	▨	☐	▨	▨	▨	▨

Note: *White box: Allowable I/O standard combinations*
Gray box: Illegal I/O standard combinations

Hot-Swap Support

Hot-swapping (also called hot plugging) is the operation of hot insertion or hot removal of a card in (or from) a powered-up system. The levels of hot-swap support and examples of related applications are described in Table 2-74. The I/Os also need to be configured in hot insertion mode if hot plugging compliance is required.

Table 2-74 **• Levels of Hot-Swap Support**

Hot Swapping Level	Description	Power Applied to Device	Bus State	Card Ground Connection	Device Circuitry Connected to Bus Pins	Example of Application with Cards that Contain Fusion Devices	Compliance of Fusion Devices
1	Cold-swap	No	–	–	–	System and card with Microsemi FPGA chip are powered down, then card gets plugged into system, then power supplies are turned on for system but not for FPGA on card.	Compliant I/Os can but do not have to be set to hot insertion mode.
2	Hot-swap while reset	Yes	Held in reset state	Must be made and maintained for 1 ms before, during, and after insertion/removal	–	In PCI hot plug specification, reset control circuitry isolates the card busses until the card supplies are at their nominal operating levels and stable.	Compliant I/Os can but do not have to be set to hot insertion mode.
3	Hot-swap while bus idle	Yes	Held idle (no ongoing I/O processes during insertion/removal)	Same as Level 2	Must remain glitch-free during power-up or power-down	Board bus shared with card bus is "frozen," and there is no toggling activity on bus. It is critical that the logic states set on the bus signal do not get disturbed during card insertion/removal.	Compliant with cards with two levels of staging. I/Os have to be set to hot insertion mode.
4	Hot-swap on an active bus	Yes	Bus may have active I/O processes ongoing, but device being inserted or removed must be idle.	Same as Level 2	Same as Level 3	There is activity on the system bus, and it is critical that the logic states set on the bus signal do not get disturbed during card insertion/removal.	Compliant with cards with two levels of staging. I/Os have to be set to hot insertion mode.

***Table 2-92* • Summary of I/O Timing Characteristics – Software Default Settings**
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = I/O Standard Dependent
Applicable to Pro I/Os

I/O Standard	Drive Strength (mA)	Slew Rate	Capacitive Load (pF)	External Resistor (Ohm)	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
3.3 V LVTTL/ 3.3 V LVCMOS	12 mA	High	35	–	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81	ns
2.5 V LVCMOS	12 mA	High	35	–	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28	ns
1.8 V LVCMOS	12 mA	High	35	–	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98	ns
1.5 V LVCMOS	12 mA	High	35	–	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37	ns
3.3 V PCI	Per PCI spec	High	10	25 [2]	0.49	2.09	0.03	0.78	1.25	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns
3.3 V PCI-X	Per PCI-X spec	High	10	25 [2]	0.49	2.09	0.03	0.77	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns
3.3 V GTL	20 mA	High	10	25	0.49	1.55	0.03	2.19	–	0.32	1.52	1.55	0.00	0.00	3.19	3.22	ns
2.5 V GTL	20 mA	High	10	25	0.49	1.59	0.03	1.83	–	0.32	1.61	1.59	0.00	0.00	3.28	3.26	ns
3.3 V GTL+	35 mA	High	10	25	0.49	1.53	0.03	1.19	–	0.32	1.56	1.53	0.00	0.00	3.23	3.20	ns
2.5 V GTL+	33 mA	High	10	25	0.49	1.65	0.03	1.13	–	0.32	1.68	1.57	0.00	0.00	3.35	3.24	ns
HSTL (I)	8 mA	High	20	50	0.49	2.37	0.03	1.59	–	0.32	2.42	2.35	0.00	0.00	4.09	4.02	ns
HSTL (II)	15 mA	High	20	25	0.49	2.26	0.03	1.59	–	0.32	2.30	2.03	0.00	0.00	3.97	3.70	ns
SSTL2 (I)	17 mA	High	30	50	0.49	1.59	0.03	1.00	–	0.32	1.62	1.38	0.00	0.00	3.29	3.05	ns
SSTL2 (II)	21 mA	High	30	25	0.49	1.62	0.03	1.00	–	0.32	1.65	1.32	0.00	0.00	3.32	2.99	ns
SSTL3 (I)	16 mA	High	30	50	0.49	1.72	0.03	0.93	–	0.32	1.75	1.37	0.00	0.00	3.42	3.04	ns
SSTL3 (II)	24 mA	High	30	25	0.49	1.54	0.03	0.93	–	0.32	1.57	1.25	0.00	0.00	3.24	2.92	ns
LVDS	24 mA	High	–	–	0.49	1.57	0.03	1.36	–	–	–	–	–	–	–	–	ns
LVPECL	24 mA	High	–	–	0.49	1.60	0.03	1.22	–	–	–	–	–	–	–	–	ns

Notes:

1. *For specific junction temperature and voltage-supply levels, refer to Table 3-6 on page 3-7 for derating values.*
2. *Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-123 on page 2-197 for connectivity. This resistor is not required during normal operation.*

Table 2-122 **• 1.8 V LVCMOS Low Slew**
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 1.7 V
Applicable to Advanced I/Os

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	Std.	0.66	15.53	0.04	1.31	0.43	14.11	15.53	2.78	1.60	16.35	17.77	ns
	–1	0.56	13.21	0.04	1.11	0.36	12.01	13.21	2.36	1.36	13.91	15.11	ns
	–2[2]	0.49	11.60	0.03	0.98	0.32	10.54	11.60	2.07	1.19	12.21	13.27	ns
4 mA	Std.	0.66	10.48	0.04	1.31	0.43	10.41	10.48	3.23	2.73	12.65	12.71	ns
	–1	0.56	8.91	0.04	1.11	0.36	8.86	8.91	2.75	2.33	10.76	10.81	ns
	–2	0.49	7.82	0.03	0.98	0.32	7.77	7.82	2.41	2.04	9.44	9.49	ns
8 mA	Std.	0.66	8.05	0.04	1.31	0.43	8.20	7.84	3.54	3.27	10.43	10.08	ns
	–1	0.56	6.85	0.04	1.11	0.36	6.97	6.67	3.01	2.78	8.88	8.57	ns
	–2	0.49	6.01	0.03	0.98	0.32	6.12	5.86	2.64	2.44	7.79	7.53	ns
12 mA	Std.	0.66	7.50	0.04	1.31	0.43	7.64	7.30	3.61	3.41	9.88	9.53	ns
	–1	0.56	6.38	0.04	1.11	0.36	6.50	6.21	3.07	2.90	8.40	8.11	ns
	–2	0.49	5.60	0.03	0.98	0.32	5.71	5.45	2.69	2.55	7.38	7.12	ns
16 mA	Std.	0.66	7.29	0.04	1.31	0.43	7.23	7.29	3.71	3.95	9.47	9.53	ns
	–1	0.56	6.20	0.04	1.11	0.36	6.15	6.20	3.15	3.36	8.06	8.11	ns
	–2	0.49	5.45	0.03	0.98	0.32	5.40	5.45	2.77	2.95	7.07	7.12	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Voltage Referenced I/O Characteristics

3.3 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-138 • **Minimum and Maximum DC Input and Output Levels**

3.3 V GTL	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL[1]	IIH[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
20 mA[3]	–0.3	VREF – 0.05	VREF + 0.05	3.6	0.4	–	20	20	181	268	10	10

Notes:

1. *IIL is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.*
3. *Currents are measured at high temperature (100°C junction temperature) and maximum voltage.*
4. *Currents are measured at 85°C junction temperature.*

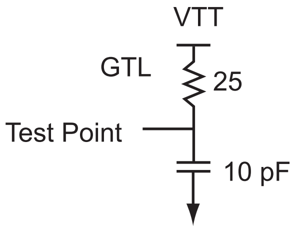


Figure 2-124 • **AC Loading**

Table 2-139 • **AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C_{LOAD} (pF)
VREF – 0.05	VREF + 0.05	0.8	0.8	1.2	10

Note: *Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

Timing Characteristics

Table 2-140 • **3.3 V GTL**
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 0.8 V

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.66	2.08	0.04	2.93	0.43	2.04	2.08			4.27	4.31	ns
–1	0.56	1.77	0.04	2.50	0.36	1.73	1.77			3.63	3.67	ns
–2	0.49	1.55	0.03	2.19	0.32	1.52	1.55			3.19	3.22	ns

Note: *For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.*

Input Register

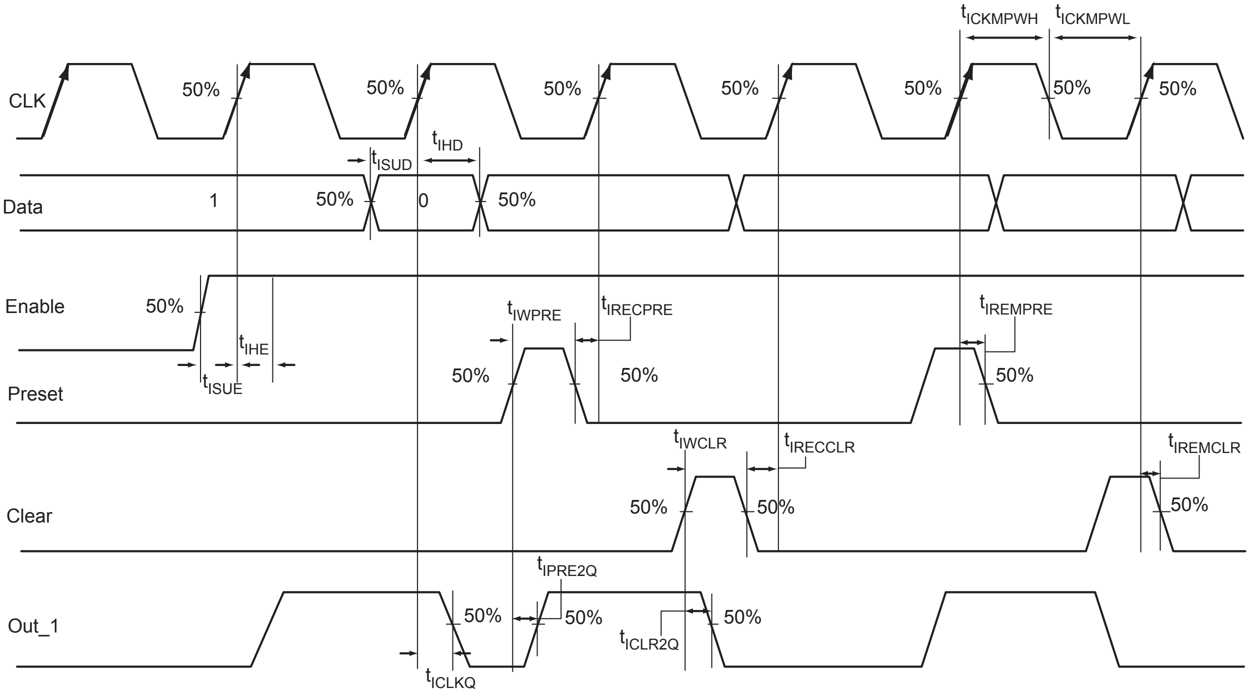


Figure 2-139 **• Input Register Timing Diagram**

Timing Characteristics

Table 2-176 **• Input Data Register Propagation Delays**
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	–2	–1	Std.	Units
t_{ICLKQ}	Clock-to-Q of the Input Data Register	0.24	0.27	0.32	ns
t_{ISUD}	Data Setup Time for the Input Data Register	0.26	0.30	0.35	ns
t_{IHD}	Data Hold Time for the Input Data Register	0.00	0.00	0.00	ns
t_{ISUE}	Enable Setup Time for the Input Data Register	0.37	0.42	0.50	ns
t_{IHE}	Enable Hold Time for the Input Data Register	0.00	0.00	0.00	ns
t_{ICLR2Q}	Asynchronous Clear-to-Q of the Input Data Register	0.45	0.52	0.61	ns
t_{IPRE2Q}	Asynchronous Preset-to-Q of the Input Data Register	0.45	0.52	0.61	ns
$t_{IREMCLR}$	Asynchronous Clear Removal Time for the Input Data Register	0.00	0.00	0.00	ns
$t_{IRECCLR}$	Asynchronous Clear Recovery Time for the Input Data Register	0.22	0.25	0.30	ns
$t_{IREMPRE}$	Asynchronous Preset Removal Time for the Input Data Register	0.00	0.00	0.00	ns
$t_{IRECPRE}$	Asynchronous Preset Recovery Time for the Input Data Register	0.22	0.25	0.30	ns
t_{IWCLR}	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.22	0.25	0.30	ns
t_{IWPRE}	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.22	0.25	0.30	ns
$t_{ICKMPWH}$	Clock Minimum Pulse Width High for the Input Data Register	0.36	0.41	0.48	ns
$t_{ICKMPWL}$	Clock Minimum Pulse Width Low for the Input Data Register	0.32	0.37	0.43	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Output Enable Register

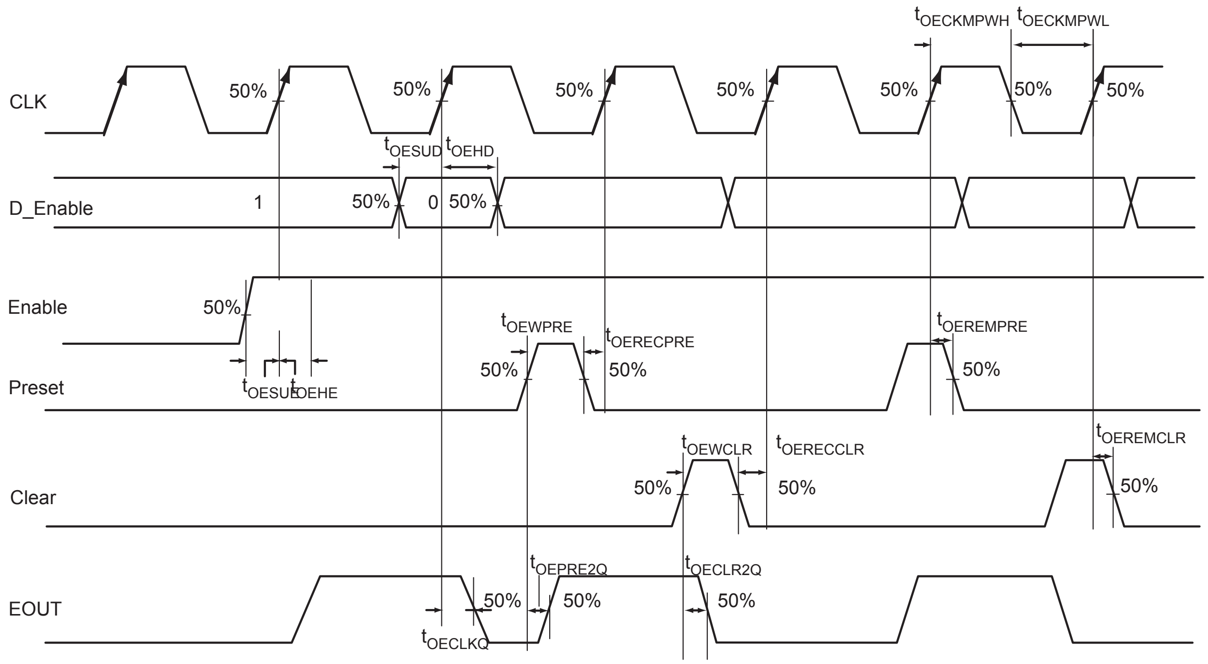


***Figure 2-141* • Output Enable Register Timing Diagram**

Timing Characteristics

***Table 2-178* • Output Enable Register Propagation Delays**
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	–2	–1	Std.	Units
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	0.44	0.51	0.59	ns
t_{OESUD}	Data Setup Time for the Output Enable Register	0.31	0.36	0.42	ns
t_{OEHD}	Data Hold Time for the Output Enable Register	0.00	0.00	0.00	ns
t_{OESUE}	Enable Setup Time for the Output Enable Register	0.44	0.50	0.58	ns
t_{OEHE}	Enable Hold Time for the Output Enable Register	0.00	0.00	0.00	ns
$t_{OECLR2Q}$	Asynchronous Clear-to-Q of the Output Enable Register	0.67	0.76	0.89	ns
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	0.67	0.76	0.89	ns
$t_{OEREMCLR}$	Asynchronous Clear Removal Time for the Output Enable Register	0.00	0.00	0.00	ns
$t_{OERECCLR}$	Asynchronous Clear Recovery Time for the Output Enable Register	0.22	0.25	0.30	ns
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	0.00	0.00	0.00	ns
$t_{OERECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	0.22	0.25	0.30	ns
t_{OEWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.22	0.25	0.30	ns
t_{OEWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.22	0.25	0.30	ns
$t_{OECKMPWH}$	Clock Minimum Pulse Width High for the Output Enable Register	0.36	0.41	0.48	ns
$t_{OECKMPWL}$	Clock Minimum Pulse Width Low for the Output Enable Register	0.32	0.37	0.43	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Output DDR

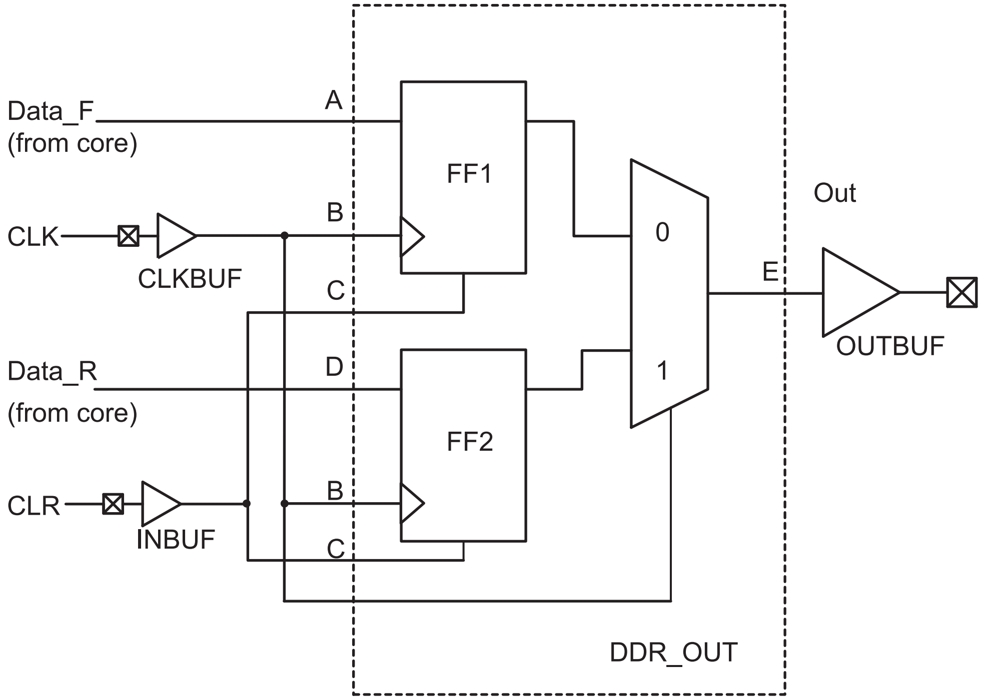


Figure 2-144 • **Output DDR Timing Model**

Table 2-181 • **Parameter Definitions**

Parameter Name	Parameter Definition	Measuring Nodes (From, To)
$t_{DDROCLKQ}$	Clock-to-Out	B, E
$t_{DDROCLR2Q}$	Asynchronous Clear-to-Out	C, E
$t_{DDROREMCLR}$	Clear Removal	C, B
$t_{DDRORECCLR}$	Clear Recovery	C, B
$t_{DDROSUD1}$	Data Setup Data_F	A, B
$t_{DDROSUD2}$	Data Setup Data_R	D, B
$t_{DDROHD1}$	Data Hold Data_F	A, B
$t_{DDROHD2}$	Data Hold Data_R	D, B

Table 3-8 • **AFS1500 Quiescent Supply Current Characteristics (continued)**

Parameter	Description	Conditions	Temp.	Min.	Typ.	Max.	Unit
IJTAG	JTAG I/O quiescent current	Operational standby[4], VJTAG = 3.63 V	T_J = 25°C		80	100	µA
			T_J = 85°C		80	100	µA
			T_J = 100°C		80	100	µA
		Standby mode[5] or Sleep mode[6], VJTAG = 0 V			0	0	µA
IPP	Programming supply current	Non-programming mode, VPUMP = 3.63 V	T_J = 25°C		39	80	µA
			T_J = 85°C		40	80	µA
			T_J = 100°C		40	80	µA
		Standby mode[5] or Sleep mode[6], VPUMP = 0 V			0	0	µA
ICCNVM	Embedded NVM current	Reset asserted, V_{CCNVM} = 1.575 V	T_J = 25°C		50	150	µA
			T_J =85°C		50	150	µA
			T_J = 100°C		50	150	µA
ICCPLL	1.5 V PLL quiescent current	Operational standby , VCCPLL = 1.575 V	T_J = 25°C		130	200	µA
			T_J = 85°C		130	200	µA
			T_J = 100°C		130	200	µA

Notes:

1. *ICC is the 1.5 V power supplies, ICC and ICC15A.*
2. *ICC33A includes ICC33A, ICC33PMP, and ICCOSC.*
3. *ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.*
4. *Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.*
5. *XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.*
6. *Sleep Mode, VCC = VJTAG = VPUMP = 0 V.*

Power per I/O Pin

***Table 3-12* • Summary of I/O Input Buffer Power (per pin)—Default I/O Software Settings**

	VCCI (V)	Static Power PDC7 (mW)[1]	Dynamic Power PAC9 (µW/MHz)[2]
Applicable to Pro I/O Banks			
Single-Ended			
3.3 V LVTTL/LVCMOS	3.3	–	17.39
3.3 V LVTTL/LVCMOS – Schmitt trigger	3.3	–	25.51
2.5 V LVCMOS	2.5	–	5.76
2.5 V LVCMOS – Schmitt trigger	2.5	–	7.16
1.8 V LVCMOS	1.8	–	2.72
1.8 V LVCMOS – Schmitt trigger	1.8	–	2.80
1.5 V LVCMOS (JESD8-11)	1.5	–	2.08
1.5 V LVCMOS (JESD8-11) – Schmitt trigger	1.5	–	2.00
3.3 V PCI	3.3	–	18.82
3.3 V PCI – Schmitt trigger	3.3	–	20.12
3.3 V PCI-X	3.3	–	18.82
3.3 V PCI-X – Schmitt trigger	3.3	–	20.12
Voltage-Referenced			
3.3 V GTL	3.3	2.90	8.23
2.5 V GTL	2.5	2.13	4.78
3.3 V GTL+	3.3	2.81	4.14
2.5 V GTL+	2.5	2.57	3.71
HSTL (I)	1.5	0.17	2.03
HSTL (II)	1.5	0.17	2.03
SSTL2 (I)	2.5	1.38	4.48
SSTL2 (II)	2.5	1.38	4.48
SSTL3 (I)	3.3	3.21	9.26
SSTL3 (II)	3.3	3.21	9.26
Differential			
LVDS	2.5	2.26	1.50
LVPECL	3.3	5.71	2.17

Notes:

1. *PDC7 is the static power (where applicable) measured on VCCI.*
2. *PAC9 is the total dynamic power measured on VCC and VCCI.*

Table 3-13 • **Summary of I/O Output Buffer Power (per pin)—Default I/O Software Settings[1]**

	C_{LOAD} (pF)	VCCI (V)	Static Power PDC8 (mW)[2]	Dynamic Power PAC10 (µW/MHz)[3]
Applicable to Pro I/O Banks				
Single-Ended				
3.3 V LVTTL/LVCMOS	35	3.3	–	474.70
2.5 V LVCMOS	35	2.5	–	270.73
1.8 V LVCMOS	35	1.8	–	151.78
1.5 V LVCMOS (JESD8-11)	35	1.5	–	104.55
3.3 V PCI	10	3.3	–	204.61
3.3 V PCI-X	10	3.3	–	204.61
Voltage-Referenced				
3.3 V GTL	10	3.3	–	24.08
2.5 V GTL	10	2.5	–	13.52
3.3 V GTL+	10	3.3	–	24.10
2.5 V GTL+	10	2.5	–	13.54
HSTL (I)	20	1.5	7.08	26.22
HSTL (II)	20	1.5	13.88	27.22
SSTL2 (I)	30	2.5	16.69	105.56
SSTL2 (II)	30	2.5	25.91	116.60
SSTL3 (I)	30	3.3	26.02	114.87
SSTL3 (II)	30	3.3	42.21	131.76
Differential				
LVDS	–	2.5	7.70	89.62
LVPECL	–	3.3	19.42	168.02
Applicable to Advanced I/O Banks				
Single-Ended				
3.3 V LVTTL / 3.3 V LVCMOS	35	3.3	–	468.67
2.5 V LVCMOS	35	2.5	–	267.48
1.8 V LVCMOS	35	1.8	–	149.46
1.5 V LVCMOS (JESD8-11)	35	1.5	–	103.12
3.3 V PCI	10	3.3	–	201.02
3.3 V PCI-X	10	3.3	–	201.02

Notes:

1. *Dynamic power consumption is given for standard load and software-default drive strength and output slew.*
2. *PDC8 is the static power (where applicable) measured on VCCI.*
3. *PAC10 is the total dynamic power measured on VCC and VCCI.*

RC Oscillator Dynamic Contribution—$P_{RC\text{-}OSC}$

Operating Mode

$P_{RC\text{-}OSC}$ = PAC19

Standby Mode and Sleep Mode

$P_{RC\text{-}OSC}$ = 0 W

Analog System Dynamic Contribution—P_{AB}

Operating Mode

P_{AB} = PAC20

Standby Mode and Sleep Mode

P_{AB} = 0 W

Guidelines

Toggle Rate Definition

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that the net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100%, as all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
  - Bit 0 (LSB) = 100%
  - Bit 1 = 50%
  - Bit 2 = 25%
  - …
  - Bit 7 (MSB) = 0.78125%
  - Average toggle rate = (100% + 50% + 25% + 12.5% + . . . 0.78125%) / 8.

Enable Rate Definition

Output enable rate is the average percentage of time during which tristate outputs are enabled. When non-tristate output buffers are used, the enable rate should be 100%.

***Table 3-16* • Toggle Rate Guidelines Recommended for Power Calculation**

Component	Definition	Guideline
α_1	Toggle rate of VersaTile outputs	10%
α_2	I/O buffer toggle rate	10%

***Table 3-17* • Enable Rate Guidelines Recommended for Power Calculation**

Component	Definition	Guideline
β_1	I/O output buffer enable rate	100%
β_2	RAM enable rate for read operations	12.5%
β_3	RAM enable rate for write operations	12.5%
β_4	NVM enable rate for read operations	0%

FG676	
Pin Number	**AFS1500 Function**
A1	NC
A2	GND
A3	NC
A4	NC
A5	GND
A6	NC
A7	NC
A8	GND
A9	IO17NDB0V2
A10	IO17PDB0V2
A11	GND
A12	IO18NDB0V2
A13	IO18PDB0V2
A14	IO20NDB0V2
A15	IO20PDB0V2
A16	GND
A17	IO21PDB0V2
A18	IO21NDB0V2
A19	GND
A20	IO39NDB1V2
A21	IO39PDB1V2
A22	GND
A23	NC
A24	NC
A25	GND
A26	NC
AA1	NC
AA2	VCCIB4
AA3	IO93PDB4V0
AA4	GND
AA5	IO93NDB4V0
AA6	GEB2/IO86PDB4V0
AA7	IO86NDB4V0
AA8	AV0
AA9	GNDA
AA10	AV1

FG676	
Pin Number	**AFS1500 Function**
AA11	AV2
AA12	GNDA
AA13	AV3
AA14	AV6
AA15	GNDA
AA16	AV7
AA17	AV8
AA18	GNDA
AA19	AV9
AA20	VCCIB2
AA21	IO68PPB2V0
AA22	TCK
AA23	GND
AA24	IO76PPB2V0
AA25	VCCIB2
AA26	NC
AB1	GND
AB2	NC
AB3	GEC2/IO87PDB4V0
AB4	IO87NDB4V0
AB5	GEA2/IO85PDB4V0
AB6	IO85NDB4V0
AB7	NCAP
AB8	AC0
AB9	VCC33A
AB10	AC1
AB11	AC2
AB12	VCC33A
AB13	AC3
AB14	AC6
AB15	VCC33A
AB16	AC7
AB17	AC8
AB18	VCC33A
AB19	AC9
AB20	ADCGNDREF

FG676	
Pin Number	**AFS1500 Function**
AB21	PTBASE
AB22	GNDNVM
AB23	VCCNVM
AB24	VPUMP
AB25	NC
AB26	GND
AC1	NC
AC2	NC
AC3	NC
AC4	GND
AC5	VCCIB4
AC6	VCCIB4
AC7	PCAP
AC8	AG0
AC9	GNDA
AC10	AG1
AC11	AG2
AC12	GNDA
AC13	AG3
AC14	AG6
AC15	GNDA
AC16	AG7
AC17	AG8
AC18	GNDA
AC19	AG9
AC20	VAREF
AC21	VCCIB2
AC22	PTEM
AC23	GND
AC24	NC
AC25	NC
AC26	NC
AD1	NC
AD2	NC
AD3	GND
AD4	NC

FG676	
Pin Number	**AFS1500 Function**
R21	IO72NDB2V0
R22	IO72PDB2V0
R23	GND
R24	IO71PDB2V0
R25	VCCIB2
R26	IO67NDB2V0
T1	GND
T2	NC
T3	GFA1/IO105PDB4V0
T4	GFA0/IO105NDB4V0
T5	IO101NDB4V0
T6	IO96PDB4V0
T7	IO96NDB4V0
T8	IO99NDB4V0
T9	IO97NDB4V0
T10	VCCIB4
T11	VCC
T12	GND
T13	VCC
T14	GND
T15	VCC
T16	GND
T17	VCCIB2
T18	IO83NDB2V0
T19	IO78NDB2V0
T20	GDA1/IO81PDB2V0
T21	GDB1/IO80PDB2V0
T22	IO73NDB2V0
T23	IO73PDB2V0
T24	IO71NDB2V0
T25	NC
T26	GND
U1	NC
U2	NC
U3	IO102PDB4V0
U4	IO102NDB4V0

FG676	
Pin Number	**AFS1500 Function**
U5	VCCIB4
U6	IO91PDB4V0
U7	IO91NDB4V0
U8	IO92PDB4V0
U9	GND
U10	GND
U11	VCC33A
U12	GNDA
U13	VCC33A
U14	GNDA
U15	VCC33A
U16	GNDA
U17	VCC
U18	GND
U19	IO74NDB2V0
U20	GDA0/IO81NDB2V0
U21	GDB0/IO80NDB2V0
U22	VCCIB2
U23	IO75NDB2V0
U24	IO75PDB2V0
U25	NC
U26	NC
V1	NC
V2	VCCIB4
V3	IO100PPB4V0
V4	GND
V5	IO95PDB4V0
V6	IO95NDB4V0
V7	VCCIB4
V8	IO92NDB4V0
V9	GNDNVM
V10	GNDA
V11	NC
V12	AV4
V13	NC
V14	AV5

FG676	
Pin Number	**AFS1500 Function**
V15	AC5
V16	NC
V17	GNDA
V18	IO77PPB2V0
V19	IO74PDB2V0
V20	VCCIB2
V21	IO82NDB2V0
V22	GDA2/IO82PDB2V0
V23	GND
V24	GDC1/IO79PDB2V0
V25	VCCIB2
V26	NC
W1	GND
W2	IO94PPB4V0
W3	IO98PDB4V0
W4	IO98NDB4V0
W5	GEC1/IO90PDB4V0
W6	GEC0/IO90NDB4V0
W7	GND
W8	VCCNVM
W9	VCCIB4
W10	VCC15A
W11	GNDA
W12	AC4
W13	VCC33A
W14	GNDA
W15	AG5
W16	GNDA
W17	PUB
W18	VCCIB2
W19	TDI
W20	GND
W21	IO84NDB2V0
W22	GDC2/IO84PDB2V0
W23	IO77NPB2V0
W24	GDC0/IO79NDB2V0

Revision	Changes	Page
Advance v1.0 (January 2008)	All Timing Characteristics tables were updated. For the Differential I/O Standards, the Standard I/O support tables are new.	N/A
	Table 2-3 • Array Coordinates was updated to change the max x and y values	2-9
	Table 2-12 • Fusion CCC/PLL Specification was updated.	2-31
	A note was added to Table 2-16 · RTC ACM Memory Map.	2-37
	A reference to the Peripheral's User's Guide was added to the "Voltage Regulator Power Supply Monitor (VRPSM)" section.	2-42
	In Table 2-25 • Flash Memory Block Timing, the commercial conditions were updated.	2-55
	In Table 2-26 • FlashROM Access Time, the commercial conditions were missing and have been added below the title of the table.	2-58
	In Table 2-36 • Analog Block Pin Description, the function description was updated for the ADCRESET.	2-82
	In the "Voltage Monitor" section, the following sentence originally had ± 10% and it was changed to +10%. The Analog Quad inputs are tolerant up to 12 V + 10%. In addition, this statement was deleted from the datasheet: Each I/O will draw power when connected to power (3 mA at 3 V).	2-86
	The "Terminology" section is new.	2-88
	The "Current Monitor" section was significantly updated. Figure 2-72 • Timing Diagram for Current Monitor Strobe to Figure 2-74 • Negative Current Monitor and Table 2-37 • Recommended Resistor for Different Current Range Measurement are new.	2-90
	The "ADC Description" section was updated to add the "Terminology" section.	2-93
	In the "Gate Driver" section, 25 mA was changed to 20 mA and 1.5 MHz was changed to 1.3 MHz. In addition, the following sentence was deleted: The maximum AG pad switching frequency is 1.25 MHz.	2-94
	The "Temperature Monitor" section was updated to rewrite most of the text and add Figure 2-78, Figure 2-79, and Table 2-38 • Temperature Data Format.	2-96
	In Table 2-38 • Temperature Data Format, the temperature K column was changed for 85°C from 538 to 358.	2-98
	In Table 2-45 • ADC Interface Timing, "Typical-Case" was changed to "Worst-Case."	2-110
	The "ADC Interface Timing" section is new.	2-110
	Table 2-46 • Analog Channel Specifications was updated.	2-118
	The "V_{CC15A} Analog Power Supply (1.5 V)" section was updated.	2-224
	The "$V_{CCPLA/B}$ PLL Supply Voltage" section is new.	2-225
	In "V_{CCNVM} Flash Memory Block Power Supply (1.5 V)" section, supply was changed to supply input.	2-224
	The "$V_{CCPLA/B}$ PLL Supply Voltage" pin description was updated to include the following statement: Actel recommends tying VCCPLX to VCC and using proper filtering circuits to decouple V_{CC} noise from PLL.	2-225
	The "$V_{COMPLA/B}$ Ground for West and East PLL" section was updated.	2-225

Revision	Changes	Page
Advance v1.0 (continued)	This change table states that in the "208-Pin PQFP" table listed under the Advance v0.8 changes, the AFS090 device had a pin change. That is incorrect. Pin 102 was updated for AFS250 and AFS600. The function name changed from $V_{CC33ACAP}$ to V_{CC33A}.	3-8
Advance v0.9 (October 2007)	In the "Package I/Os: Single-/Double-Ended (Analog)" table, the AFS1500/M7AFS1500 I/O counts were updated for the following devices: FG484: 223/109 FG676: 252/126	II
	In the "108-Pin QFN" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pin: B25	3-2
	In the "180-Pin QFN" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: B29 AFS250: B29	3-4
	In the "208-Pin PQFP" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: 102 AFS250: 102	3-8
	In the "256-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS090: T14 AFS250: T14 AFS600: T14 AFS1500: T14	3-12
Advance v0.9 (continued)	In the "484-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS600: AB18 AFS1500: AB18	3-20
	In the "676-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to V_{CC33A} for the following pins: AFS1500: AD20	3-28
Advance v0.8 (June 2007)	Figure 2-16 • Fusion Clocking Options and the "RC Oscillator" section were updated to change GND_OSC and VCC_OSC to GNDOSC and VCCOSC.	2-20, 2-21
	Figure 2-19 • Fusion CCC Options: Global Buffers with the PLL Macro was updated to change the positions of OADIVRST and OADIVHALF, and a note was added.	2-25
	The "Crystal Oscillator" section was updated to include information about controlling and enabling/disabling the crystal oscillator.	2-22
	Table 2-11 · Electrical Characteristics of the Crystal Oscillator was updated to change the typical value of $I_{DYNXTAL}$ for 0.032–0.2 MHz to 0.19.	2-24
	The "1.5 V Voltage Regulator" section was updated to add "or floating" in the paragraph stating that an external pull-down is required on TRST to power down the VR.	2-41
	The "1.5 V Voltage Regulator" section was updated to include information on powering down with the VR.	2-41